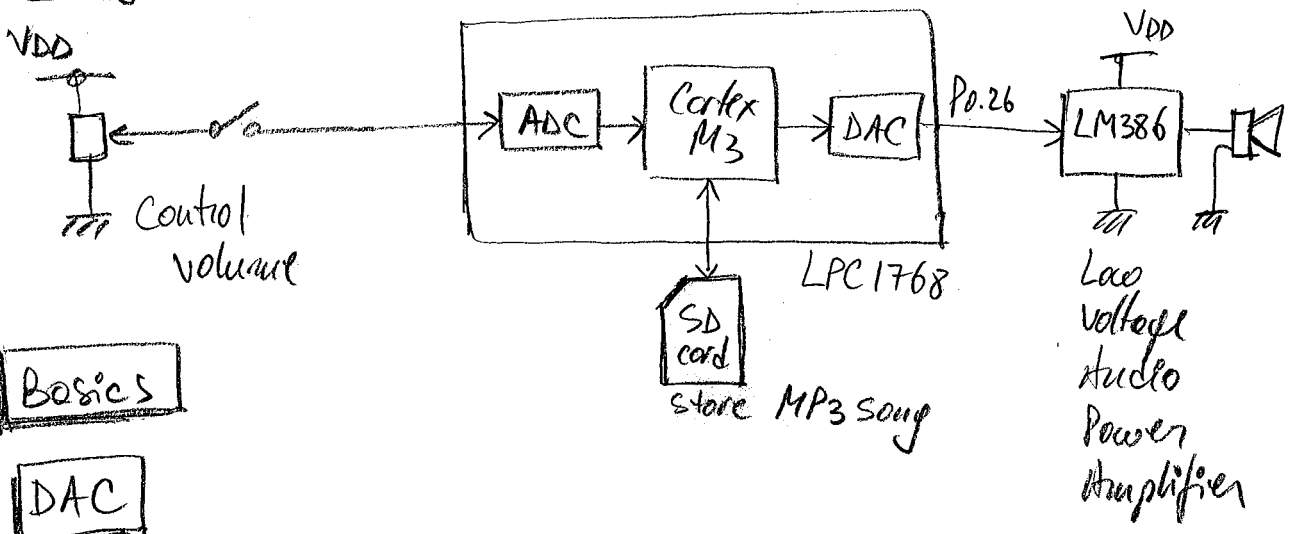
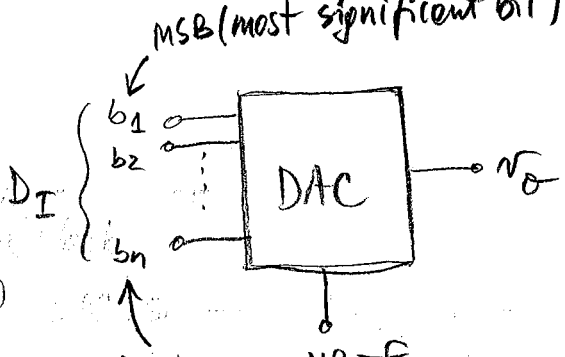
Introduction to (1st talk about IRQ vs. FIQ) Recall T13

Digital to Analog Converters DAC and Analog to Digital Converters ADC

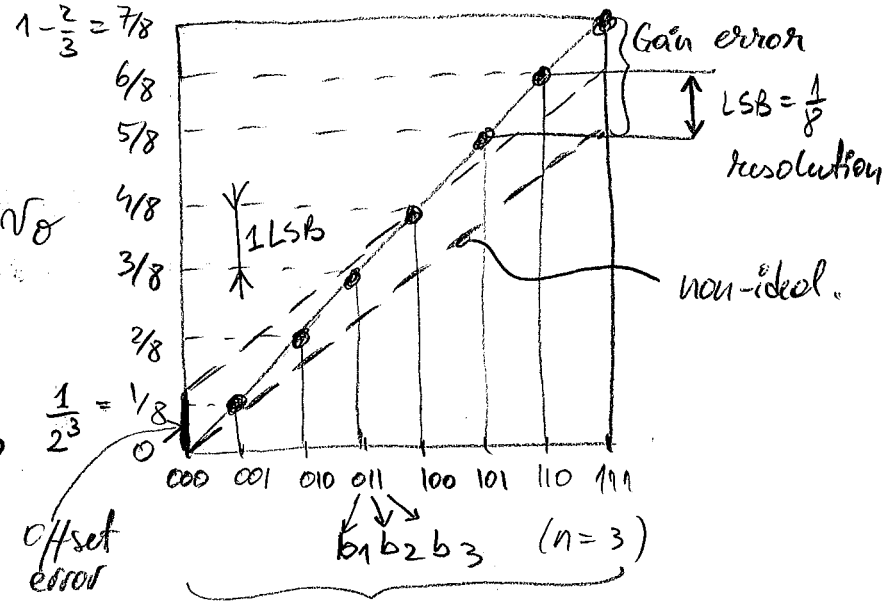


A Basics

(1) DAC



Example: $(b_1 b_2 b_3 b_4)_2 = (0111)_2 = 7_{10}$



2^n points => 2^n output values

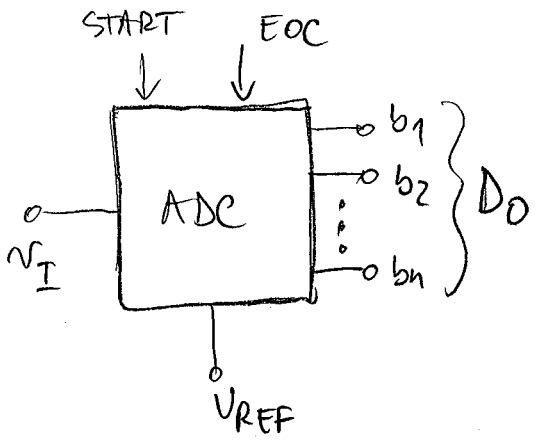
$$v_O = k V_{REF} \cdot D_I = k V_{REF} \left(b_1 \cdot \frac{1}{2} + b_2 \frac{1}{2^2} + \dots + b_n \frac{1}{2^n} \right) = k \cdot V_{REF} \cdot \sum_{i=1}^{n} \frac{b_i}{2^i}$$

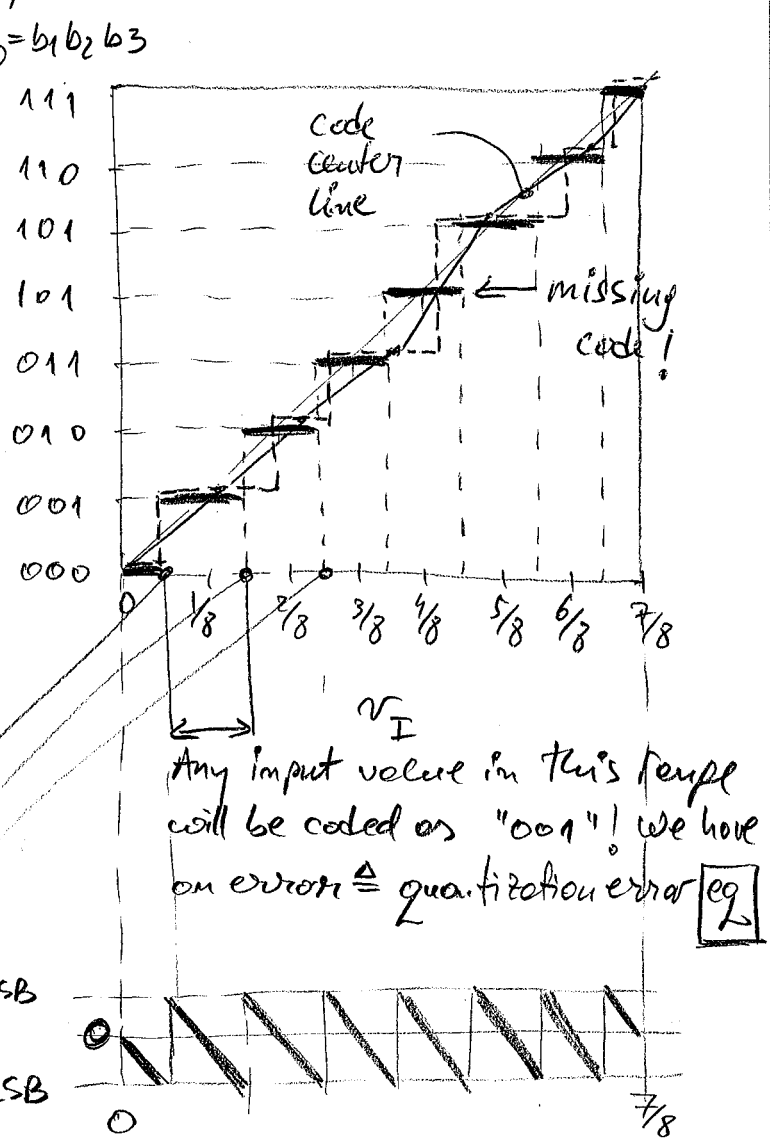
(MSB: $b_1 \cdot \frac{1}{2}$, LSB: $b_n \frac{1}{2^n}$)

Definitions:
- FSR ≡ full scale range $V_{FSR} = k V_{REF}$
- FSV ≡ full scale value $V_{FSV} = (1-2^{-n}) V_{FSR}$
- LSB ≡ Resolution $\frac{V_{FSR}}{2^n}$

- This is called a multiplying DAC because v_O is obtained by multiplying $V_{REF} \times D_I$: $D_I = b_1 \cdot 2^{-1} + b_2 \cdot 2^{-2} + \dots + b_n \cdot 2^{-n}$

(2) **ADC** provides the inverse function of DAC!





$$D_O = b_1 \frac{1}{2} + b_2 \frac{1}{2^2} + \dots + b_n \frac{1}{2^n}$$

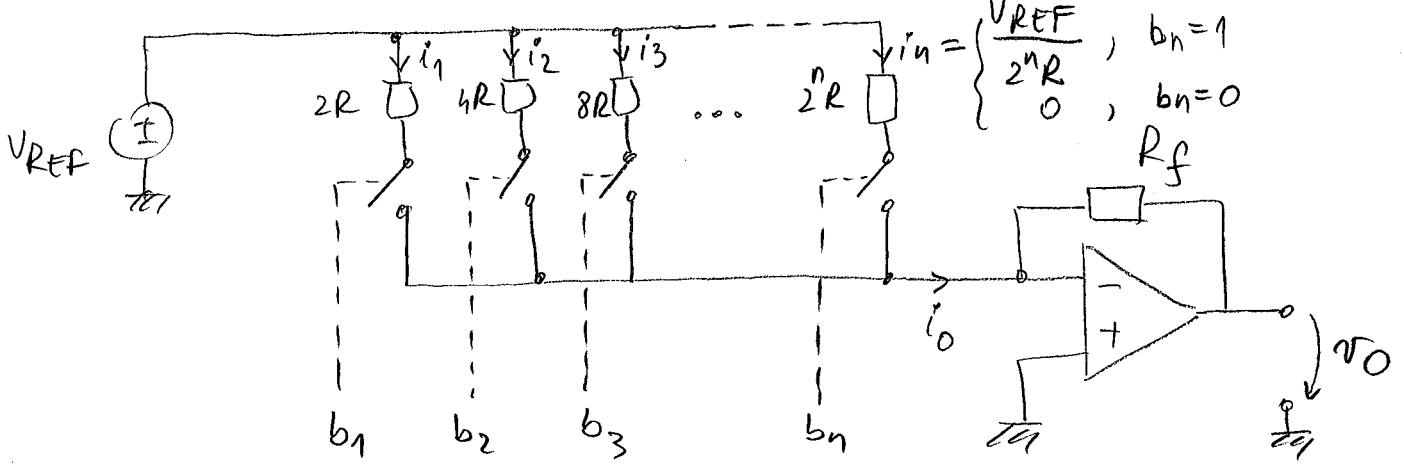
$$= \frac{V_I}{k \cdot V_{REF}} = \frac{V_I}{V_{FSR}}$$

ideally these transitions take place at odd number of $\frac{1}{2}$LSB; if not, then we have nonlinearities (errors)

Conversion time ≙ time for ADC to complete the transition!

B DA Techniques

(a) Weighted resistor DAC

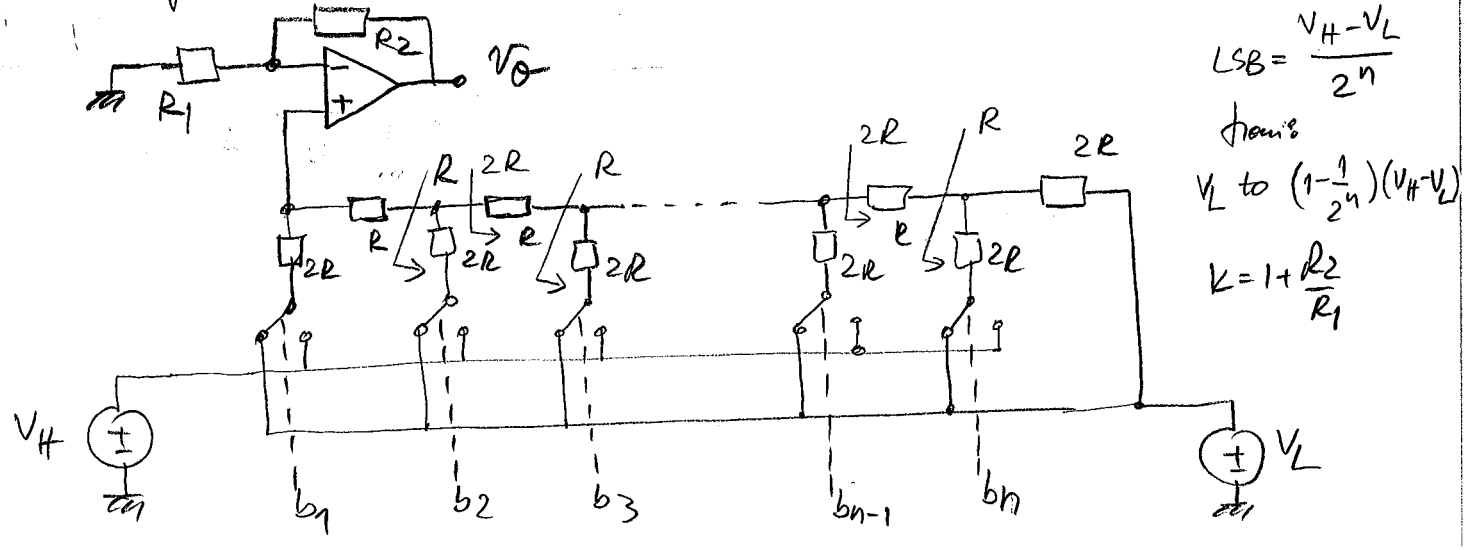


$$\frac{v_o}{R_f} = -i_o$$

$$v_o = -\frac{R_f}{R} \cdot V_{REF}\left(b_1 \frac{1}{2} + b_2 \frac{1}{4} + b_3 \frac{1}{2^3} + \ldots + b_n \frac{1}{2^n}\right)$$

Drawbacks – monotonic switch resistance
– wide spread of resistor values (exponential increase!)

(b) weighted-capacitor DAC
(c) Potentiometric DAC
(d) Voltage-mode R-2R ladder



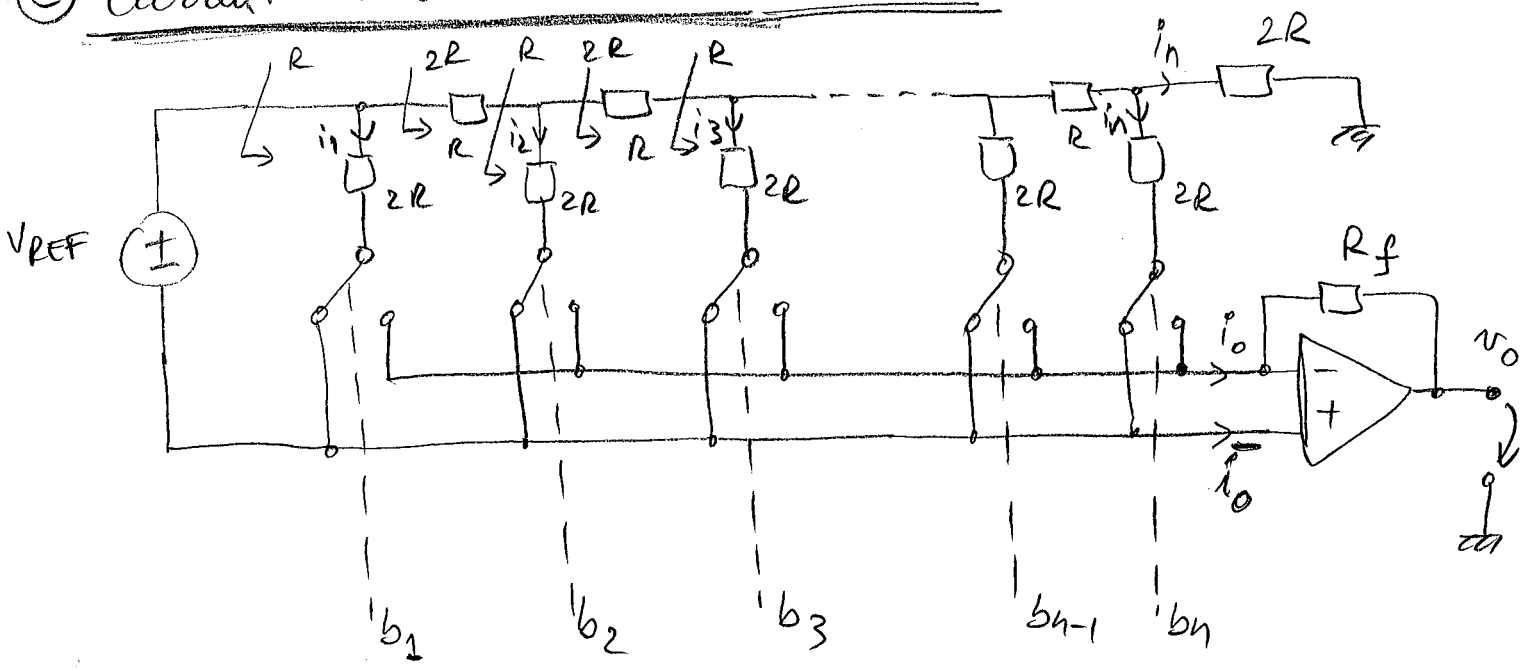
$$LSB = \frac{V_H - V_L}{2^n}$$

from V_L to $\left(1 - \frac{1}{2^n}\right)(V_H - V_L)$

$$K = 1 + \frac{R_2}{R_1}$$

Advantage: we can interpolate between only V_L, V_H !

ⓒ Current-mode R-2R ladder based DA



$$\begin{cases} i_1 = \dfrac{V_{REF}}{2R} = \dfrac{V_{REF}}{R}\cdot\dfrac{1}{2} \\ i_2 = \dfrac{V_{REF}}{4R} = \dfrac{V_{REF}}{R}\cdot\dfrac{1}{2^2} \\ \dots \\ i_n = \dfrac{V_{REF}}{R}\cdot\dfrac{1}{2^n} \end{cases}$$

$$\frac{v_o}{R_f} = -i_o$$

$$v_o = -R_f \cdot i_o$$

OBS:- Note that $i_o + \bar{i}_o = (1-2^{-n})\cdot\dfrac{V_{REF}}{R}$

regardless of $D_I = b_1 b_2 b_3 \dots b_n$!

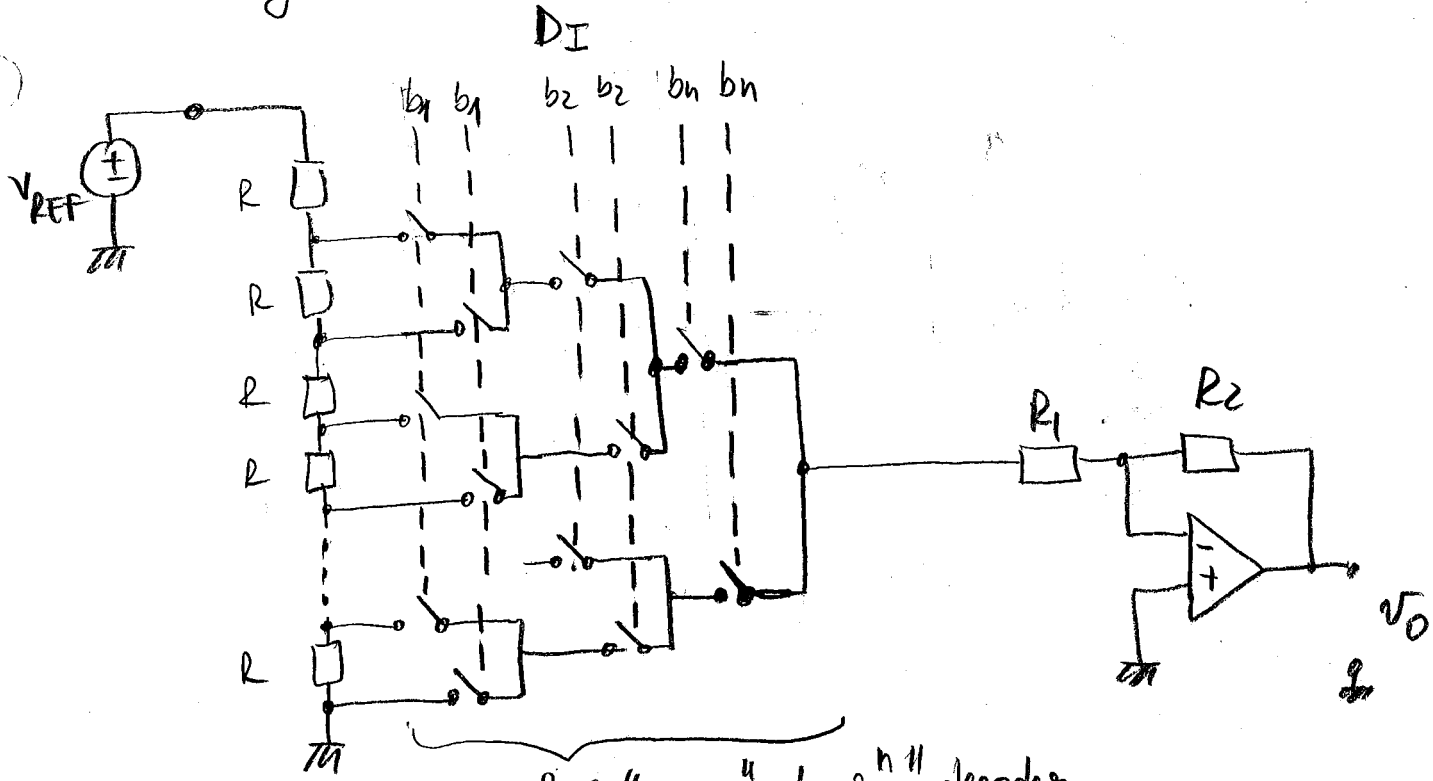
- $\bar{i}_o$ is said to be complementary to i_o

$$v_o = -\left(\frac{R_f}{R}\right) V_{REF}\cdot\left(b_1\frac{1}{2} + b_2\frac{1}{2^2} + \dots + b_n\frac{1}{2^n}\right)$$

$$\triangleq K = -\frac{R_f}{R}$$

$$\boxed{v_o = K V_{REF}\left(b_1\frac{1}{2} + b_2\frac{1}{2^2} + \dots + b_n\frac{1}{2^n}\right)}$$

(f) R-String architecture (used inside LPC1768)



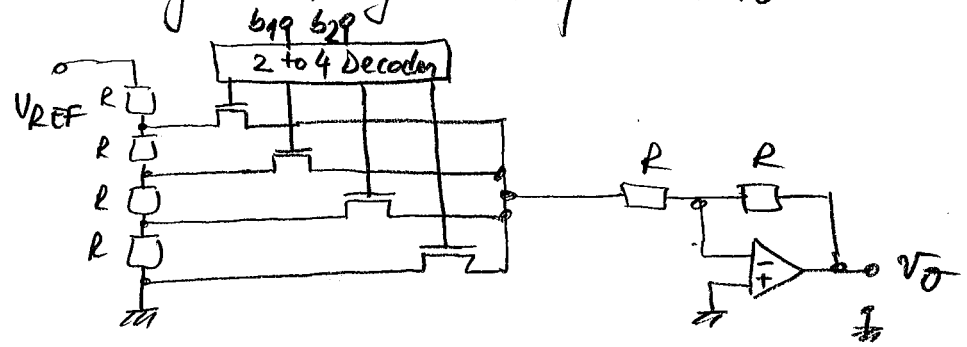
Advantages: – simple (needs only identical resistors)
– fast for < 8–10 bits
– monotonic (inherently)
– compatible w/ purely digital technologies
– low power

Disadvantages:

– 2^n resistors and 2^n switches for n bits.
⇒ high element count, high area!

– high settling time for $n > 10$

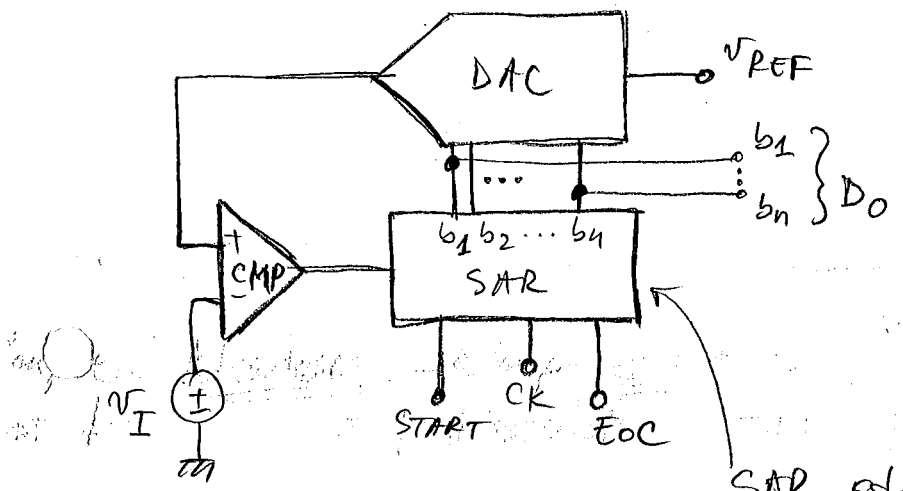
Example:



C AD techniques

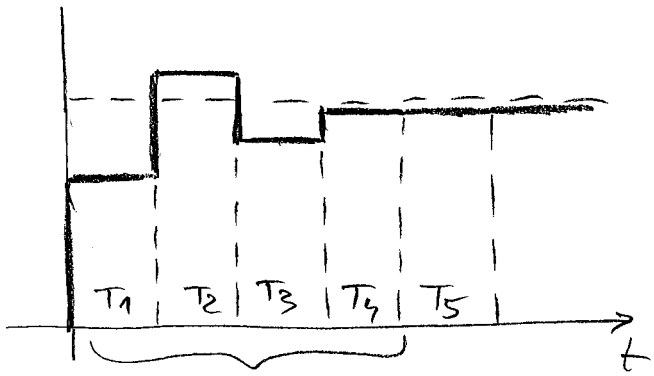
a) DAC based AD conversion:
"successive-approximation converter" ← uses SAR (successive approximation register)
b) charge-redistribution converter
c) flash converter
d) subranging converter
e) integrating-type converters.

a) DAC based A-D Conversion (used by LPC 1768)



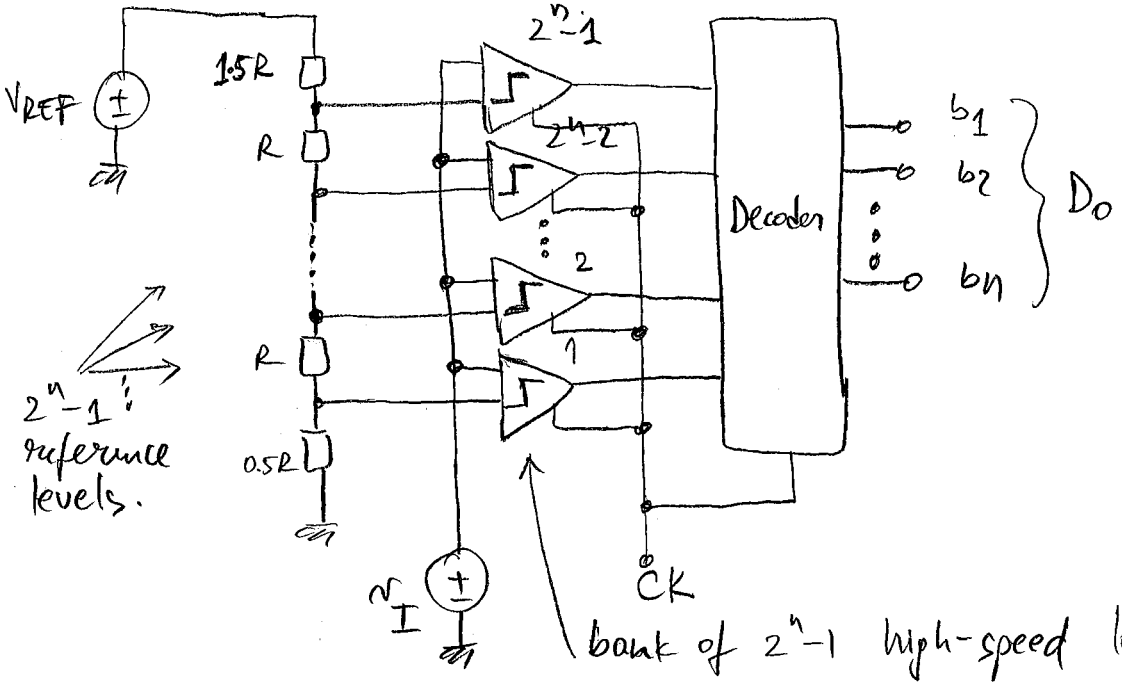
SAR adjusts DAC's input code until DAC's output comes within ½ LSB of input voltage V_I!

Example:



4 clock cycles.

c) Flash converters



bank of 2^n-1 high-speed latched comparators!

LPC 1768

DAC - 10 bit
- resistor string architecture
- maximum update rate 1 MHz

ADC: - 12-bit successive approximation.
- conversion rate 200 kHz

IRQ vs. FIQ fast interrupt - (available in ARM 7/9/10/11)
- not available in cortex-M3
- however, interrupt priority handling and nested interrupt support are included in the "interrupt support"

- FIQ - fast interrupt, higher priority (than IRQ) which is prioritized by disabling IRQ during request servicing; patented by ARM.
- IRQ - normal priority